Wafer Connector pitch 1mm series

1. Scope

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This specification covers the Wafer Connector FWF10001/FWF10002 Series

2. Ordering information

Refer to the drawing.

3. Connector dimensions

Refer to the drawing.

4. Material

Housing: PA9T (UL 94V-0)

Color: Natural
Terminal: Copper alloy
Plating: Tin plated
Solder tab: Copper alloy
Plating: Tin plated

5. Accommodated P.C.B layout

Refer to the drawing.

6. Rating

Operating voltage(Max.) 50V AC/DC Current rating(Max.) 1.0A AC/DC

Temperature range-operating -25°C -- +85°C(Including terminal temperature rese)

7. Performance

Test item	Requirement	Test Condition					
Electrical Performance							
Contact Resistance	20mΩ Max.	Mate connectors, measure by dry circuit, 20mV Max., 10mA Mated Length : 50mm (AWG. #28) (Based upon JIS C5402 5.4)					
Insulation Resistance 100 M Ω Min.		Mate connectors, apply 500V DC between adjacent terminal or ground. (Based upon JIS C5402 5.2/MIL-STD-202 method 302 Cond.B)					
Dielectric Strength	No breakdown and flashove	Mate connectors, apply 500V AC for 1 minute between adjacent terminal or ground. (Based upon JIS C5402 5.1/MIL-STD-202 Method 301)					



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Test item	Requirement					Test Condition			
	Requirement					rest Condition			
Contact resistance on crimped portion	10mΩ Max.					Crimp the maximum applicable wire on to the terminal, measure by dry circuit, 20mV MAX., 10mA. Wire Length: 50mm (AWG. #28)			
Mechanical Performance									
Insertion force and withdrawal force	Refer to paragraph 9					Insert and withdraw connectors at a speed of 25± 3mm/minute.			
	Wire size #28 #30 #32				#32				
	1	width		0.7±0.1					
		height	0.58~ 0.62	0.55~ 0.60	0.45~ 0.58				
Crimping pull out force		width		0.70	1	Fix the crimped terminal, apply axial pull out force on the wire at a speed of 25±3mm/minute.			
		height	1.10	1.00	0.90	(Based upon JIS C5402 6.22)			
	Crin	np strength	1.5kg min.	0.8kg min.	0.5kg min.				
	1. Conductor (mm) 2: Insulation (mm)								
Terminal Insertion Force	0.5kgf Max.					Insert the crimped terminal into the housing at a speed of 25 \pm 3mm/min.			
Terminal/ Housing retention force	0.5kgf Min.					Apply axial pull out force at a speed of 25±3mm/minute on the terminal assembled In the housing.			
Pin Retention Force	0.5kgf Min.					Apply axial push force at a speed of 25±3mm/minute on the contact pin assembled in the base wafer.			
		En	vironn	nental F	Perforn	nance and others			
Repeated Insertion and Withdrawal	Contact Resistance 40mΩ Max.			Max.		Mate connector up to 30 cycles repeatedly at a rate of 10 cycles/ minute. After which test the contact resistance.			
Temperature Rise	30°C Max.					Apply rated current load on mated connector in series-connection. Measure change of temperature on contact us thermocouples for 4 hours. (Based upon UL 1977)			
Vibration	Appearance No Damage					Amplitude: 1.52mm P.P			
	Contact Resistance 40mΩ Max.			Max.		Sweep time: 10-55-10Hz/minute Duration: 2 hours in each X \ Y \ Z axlals.			
	Discontinuity 1μ sec Max.					(Based upon MIL-STD-202 method 201A)			

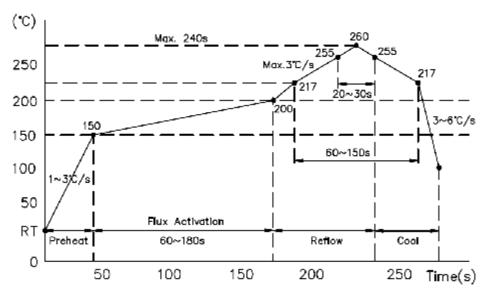


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Test item	Require	ement	Test Condition		
Shock	Appearance	No Damage	50G, 3 strokes in each X、Y、Z. axlals. (Based upon JIS C0041)		
	Contact Resistance	40mΩ Max.			
	Discontinuity	1μ sec Max.			
Heat resistance	Appearance	No Damage	Mated connector shall be placed in an oven for 96 ±4 hours at		
	Contact Resistance	40mΩ Max.	+85±2°C. (Based upon JIS C5402 7.8)		
Cold resistance	Appearance	No Damage	Mated connector shall be placed in a temperature chamber for 96±4 hours at -25±2°C		
	Contact Resistance	40mΩ Max.	(Based upon JIS C5402 7.9)		
	Appearance	No Damage	Material composter shall be placed in a burnidity observer		
Humidity	Contact Resistance	40mΩ Max.	Mated connector shall be placed in a humidity chamber on the following conditions. Temperature: 40±2°C		
numuny	Dielectric Strength	500V,AC/min	Relative humidity: 90~95% Duration : 240 Hours (Based upon MIL-STD-202 Method 103 Cond.A)		
	Insulation Resistance	10MΩ Min.	(based upon Mile-316-202 Method 103 Cond.A)		
	Appearance	No Damage	Mated connector shall be set to temperature cycling for 5		
Tomporature eveling	Contact Resistance	40mΩ Max.	cycles of which 1 cycle consists of: 1>.+25°C ~ 3 minutes 2>25°C ~ 30 minutes		
Temperature cycling	Dielectric Strength	500V,AC/min	3>.+25°C ~ 3 minutes 4>.+85°C ~ 30 minutes		
	Insulation Resistance	10MΩ Min.	(Based upon JIS C5402 7.2)		
Salt Spray	Appearance	No Damage	Mated connector shall be placed in a salt spray chamber o the following conditions. Salt Solution Density: 5±1% Temperature: 35±2°C Duration: First punch, second plate: 24±4 Hours First plate, second punch: 8±2 Hours Remarks: we make sure the important area		
	Contact Resistance	40mΩ Max.			
Solderability	95% of immersed area voids nor pin holes.	a must show no	Immerse fluxed soldered section of contact pin into a solder bath for 3±0.5sec Temperature: 230±5°C		
Resistance to soldering heat	No Damage in appear	rance	Mated connector shall be dipped on solder bath for 5±0.5sec Temperature: 260±5°C		



8. Reference infrared reflow condition



Standard JEDEC temperature profile (Lead free reflow)

9. Insertion force and withdrawal force

(Unit:kgf)

Circuits	Insertion (Max.)	Withdrawal (Min.)	
	Initial	Initial	30th
2	2.04	0.20	0.20
3	2.04	0.20	0.20
4	2.04	0.20	0.20
5	3.06	0.30	0.30
6	3.06	0.30	0.30
7	3.06	0.30	0.30
8	4.08	0.40	0.40
9	4.08	0.40	0.40
10	4.08	0.40	0.40
11	5.10	0.50	0.50
12	5.10	0.50	0.50
13	5.10	0.50	0.50
14	6.12	0.60	0.60
15	6.12	0.60	0.60
16	6.12	0.60	0.60
17	7.14	0.70	0.70
18	7.14	0.70	0.70
19	7.14	0.70	0.70
20	8.16	0.80	0.80